



# NPN SILICON PLANAR TRANSISTOR

# 2N3501P



TO-39 Metal Can Package

## Amplifier Transistor

#### ABSOLUTE MAXIMUM RATINGS (at $T_A=25^{\circ}C$ , unless otherwise specified)

DESCRIPTION	SYMBOL	VALUE	UNIT	
Collector Emitter Voltage	V <sub>CEO</sub>	150	V	
Collector Base Voltage	V <sub>CBO</sub>	150	V	
Emitter Base Voltage	V <sub>EBO</sub>	6	V	
Collector Current Continuous	I <sub>C</sub>	300	mA	
Power Dissipation @ T <sub>A</sub> = 25°C		1	W	
Derate Above 25°C	P <sub>D</sub>	5.71	mW/°C	
Power Dissipation @ T <sub>c</sub> = 25°C	_	5	W	
Derate Above 25°C	P <sub>D</sub>	28.6	mW/°C	
Operating and Storage Junction Temperature Range	T <sub>j</sub> , T <sub>stg</sub>	- 65 to +200	°C	

#### ELECTRICAL CHARACTERISTICS (T<sub>a</sub>=25°C unless specified otherwise )

DESCRIPTION	SYMBOL	TEST CONDITION	VALUE	UNIT
Junction to Ambient	R <sub>th(J-A)</sub>		175	°C/W
Junction to Case	R <sub>th(J-C)</sub>		35	°C/W

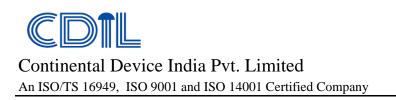




#### ELECTRICAL CHARACTERISTICS (T<sub>a</sub>=25°C unless specified otherwise )

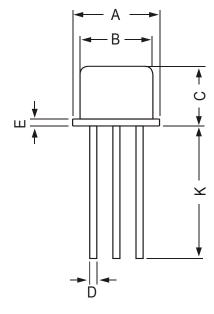
DESCRIPTION SYMBOL TES		TEST CONDITION	MIN	TYP	MAX	UNIT	
Collector Emitter Breakdown Voltage	$V_{CEO}$	I <sub>C</sub> =10mA, I <sub>B</sub> =0	150			V	
Collector Base Breakdown Voltage	V <sub>CBO</sub>	Ι <sub>c</sub> =10μΑ, Ι <sub>E</sub> =0	150			V	
Emitter Base Breakdown Voltage	$V_{\text{EBO}}$	Ι <sub>Ε</sub> =10μΑ, Ι <sub>C</sub> =0	6			V	
Collector Cut Off Current	I <sub>CBO</sub>	V <sub>CB</sub> =75V, I <sub>E</sub> =0			50	nA	
Emitter Cut Off Current	I <sub>EBO</sub>	$V_{EB}$ =4V, I <sub>C</sub> =0			25	nA	
		I <sub>C</sub> =10mA, I <sub>B</sub> =1mA			0.2	V	
Collector Emitter Saturation Voltage	$V_{\text{CE (sat)}}$	I <sub>C</sub> =50mA, I <sub>B</sub> =5mA			0.25	V	
		I <sub>C</sub> =150mA, I <sub>B</sub> =15mA			0.4	V	
Base Emitter Saturation Voltage		I <sub>C</sub> =10mA, I <sub>B</sub> =1mA			0.8	V	
	$V_{\text{BE (sat)}}$	I <sub>C</sub> =50mA, I <sub>B</sub> =5mA			0.9	V	
		I <sub>C</sub> =150mA, I <sub>B</sub> =15mA			1.2	V	
DC Current Gain		I <sub>C</sub> =0.1mA, V <sub>CE</sub> =10V	35				
		I <sub>C</sub> =1mA, V <sub>CE</sub> =10V	50				
	*h <sub>FE</sub>	I <sub>C</sub> =10mA, V <sub>CE</sub> =10V	75				
		I <sub>C</sub> =150mA, V <sub>CE</sub> =10V	40		300		
		I <sub>C</sub> =300mA, V <sub>CE</sub> =10V	10				
Transition Frequency	f <sub>T</sub>	V <sub>CE</sub> =10V, I <sub>C</sub> =10mA, f=1KHz	150			MHz	

\*Pulse Test: Pulse Width = 300µs, Duty Cycle ≤ 2%

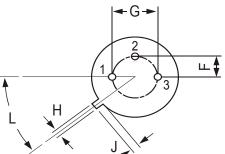




## **TO-39 Metal Can Package**



	DIM	MIN	MAX
All dimensions are in mm	А	8.50	9.39
	В	7.74	8.50
	С	6.09	6.60
	D	0.40	0.53
	E	_	0.88
	F	2.41	2.66
	G	4.82	5.33
	Н	0.71	0.86
	J	0.73	1.02
	К	12.70	
All c	L	42 DEG	48 DEG





PIN CONFIGURATION

1. EMITTER

BASE
COLLECTOR

# Packing Detail

PACKAGE	STANDARD PACK		INNER CARTON BOX		CUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
TO-39	500 pcs/polybag	540 gm/500 pcs	3" x 7.5" x 7.5"	20K	17" x 15" x 13.5"	32K	40 kgs



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**Customer Notes** 



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